International workshop on graphene/SiC and related materials 2016

2016/8/10 Wed. 13:55~17:30 @Hall on the 2nd floor in Research Institute building II, Nagoya University.

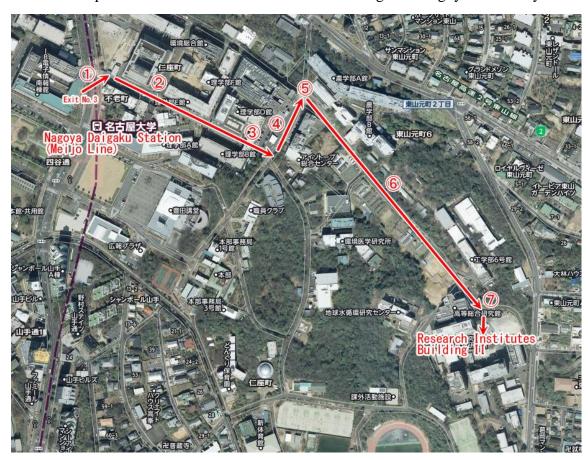
13:55~14:00	Opening remarks	Wataru Norimatsu (Nagoya University)
14:00~14:30	Invited talk 1 "Robust Phonon-Silicon Carbide"	Thomas Seyller (Technical University of Chemnitz) -Plasmon Coupling in Quasi-Freestanding Graphene on
14:30~15:00	Invited talk 2 "Liquid-phase grasilicon through a	Francesca Iacopi (Griffith University) rowth of high-quality graphene from silicon carbide on catalytic alloy"
15:00~15:15	Invited talk 3 "Sub 2D structure	Satoru Tanaka (Kyushu University) es on SiC facets"
15:15~15:30	Invited talk 4 "Si intercalation i	Anton Visikovskiy (Kyushu University) in 6R3/SiC interfaces"
15:30~16:10	Poster session (by Nagoya Univ. students) & Coffee break	
16:10~16:40	-	Hiroki Hibino (Kwansei Gakuin University) vsis of heterostructures of 2D materials by low-energy opy and diffraction"
16:40~17:10	Invited talk 6 "First-principles	Hiroyuki Kageshima (Shimane University) Study of Initial Stage of MoS2 Crystal Growth"
17:10~17:30	Lab tour of "new" Kusunoki laboratory	

Venue

Address of Nagoya University:

Furo-cho, Chikusa-ku, Nagoya-shi, Aichi, 464-8603, Japan.

The workshop will be held in Research Institutes Building II in Nagoya University.



When you get off at Nagoya Daigaku Station in Meijo line,

- 1. Go out the exit No. 3, and cross the street.
- 2. Walk straight along the road between the ES building and Information and Communication building.
- 3. Pass through the Building-C of School of Science.
- 4. Turn left at Radioisotope Research Center.
- 5. Turn right at Noyori Memorial Material Science Builing.
- 6. Go straight, looking the farm and field of School of Agriculture on your right.
- 7. After passing the Institute for Advanced Research, you can find the Research Institutes Building II on your right front.